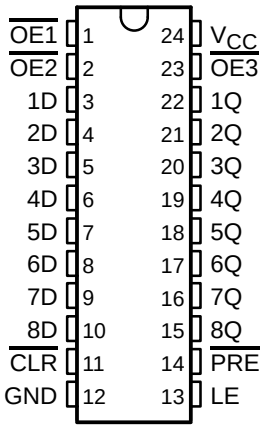
- **3-State Buffer-Type Outputs Drive Bus Lines Directly**
- **Bus-Structured Pinout**
- **Provides Extra Bus-Driving Latches Necessary for Wider Address/Data Paths or Buses With Parity**
- **Buffered Control Inputs to Reduce dc Loading Effects**
- **Power-Up High-Impedance State**
- **Package Options Include Plastic Small-Outline (DW) Packages and Standard Plastic (NT) 300-mil DIPs**

DW OR NT PACKAGE
(TOP VIEW)



description

This 8-bit latch features 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. This device is particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

The eight latches are transparent D-type latches. The device has noninverting data (D) inputs and provides true data at its outputs.

Because the clear ($\overline{CLR}$) and preset ($\overline{PRE}$) inputs are independent of the clock (CLK) input, taking $\overline{CLR}$ low causes the eight Q outputs to go low. Taking $\overline{PRE}$ low causes the eight Q outputs to go high. When both $\overline{PRE}$ and $\overline{CLR}$ are taken low, the outputs follow the preset condition.

The buffered output-enable ($\overline{OE1}$, $\overline{OE2}$, and $\overline{OE3}$) inputs can be used to place the eight outputs in either a normal logic state (high or low levels) or a high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without interface or pullup components.

The output enables do not affect the internal operation of the latches. Previously stored data can be retained or new data can be entered while the outputs are in the high-impedance state.

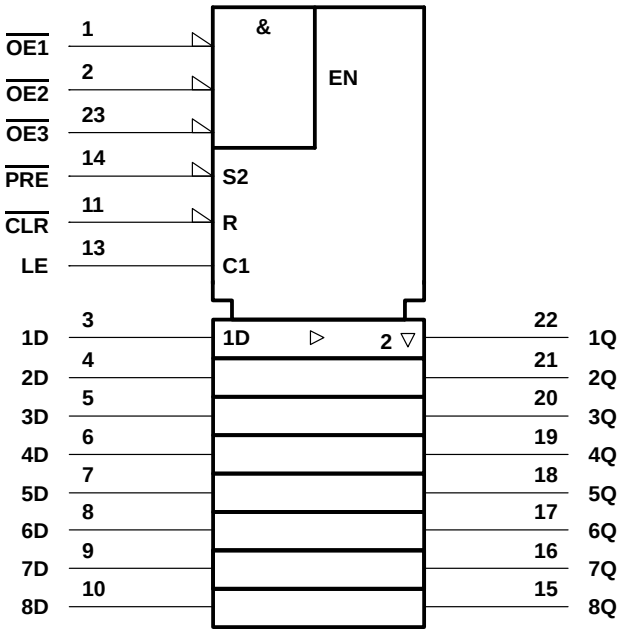
The -1 version of the SN74ALS845 is identical to the standard version, except that the recommended maximum I_{OL} for the -1 version is increased to 48 mA.

The SN74ALS845 is characterized for operation from 0°C to 70°C.

FUNCTION TABLE

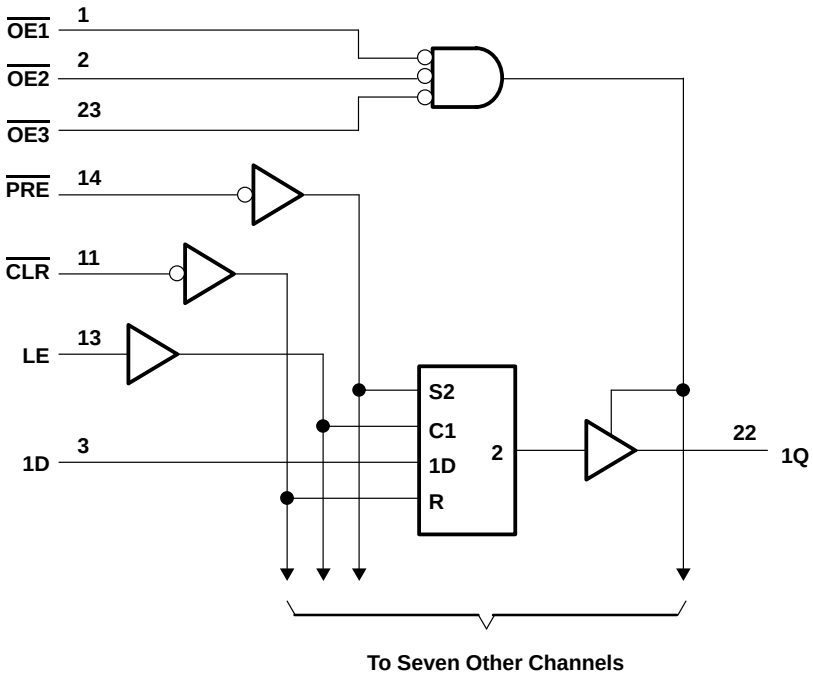
INPUTS							OUTPUT
$\overline{PRE}$	$\overline{CLR}$	$\overline{OE1}$	$\overline{OE2}$	$\overline{OE3}$	LE	D	Q
L	X	L	L	L	X	X	H
H	L	L	L	L	X	X	L
H	H	L	L	L	H	L	L
H	H	L	L	L	H	H	H
H	H	L	L	L	L	L	Q_0
X	X	X	X	H	X	X	Z
X	X	X	H	X	X	X	Z
X	X	H	X	X	X	X	Z

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V_{CC} . . . . . 7 V
Input voltage, V_I . . . . . 7 V
Voltage applied to a disabled 3-state output . . . . . 5.5 V
Operating free-air temperature range, T_A . . . . . 0°C to 70°C
Storage temperature range . . . . . –65°C to 150°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

			MIN	NOM	MAX	UNIT
V_{CC}	Supply voltage		4.5	5	5.5	V
V_{IH}	High-level input voltage		2			V
V_{IL}	Low-level input voltage				0.8	V
I_{OH}	High-level output current				–2.6	mA
I_{OL}	Low-level output current				24	mA
					48‡	
t_w	Pulse duration	$\overline{CLR}$ or $\overline{PRE}$ low	35			ns
		LE high	20			
t_{su}	Setup time, data before LE↓		10			ns
t_h	Hold time, data after LE↓		5			ns
T_A	Operating free-air temperature		0		70	°C

‡ Applies only to the -1 version and only if V_{CC} is between 4.75 V and 5.25 V

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		MIN	TYP§	MAX	UNIT
V_{IK}	V_{CC} = 4.5 V,	I_I = –18 mA			–1.2	V
V_{OH}	V_{CC} = 4.5 V to 5.5 V,	I_{OH} = –0.4 mA	V_{CC} –2			V
	V_{CC} = 4.5 V,	I_{OH} = –2.6 mA	2.4	3.2		
V_{OL}	V_{CC} = 4.5 V	I_{OL} = 12 mA		0.25	0.4	V
		I_{OL} = 24 mA		0.35	0.5	
		I_{OL} = 48 mA‡		0.35	0.5	
I_{OZH}	V_{CC} = 5.5 V,	V_O = 2.7 V			20	µA
I_{OZL}	V_{CC} = 5.5 V,	V_O = 0.4 V			–20	µA
I_I	V_{CC} = 5.5 V,	V_I = 7 V			0.1	mA
I_{IH}	V_{CC} = 5.5 V,	V_I = 2.7 V			20	µA
I_{IL}	V_{CC} = 5.5 V,	V_I = 0.4 V			–0.1	mA
I_O¶	V_{CC} = 5.5 V,	V_O = 2.25 V	–30		–112	mA
I_{CC}	V_{CC} = 5.5 V	Outputs high		21	36	mA
		Outputs low		41	67	
		Outputs disabled		25	42	

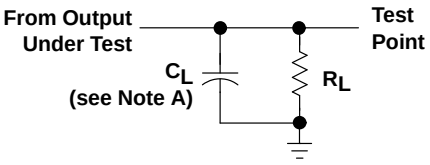
‡ Applies only to the -1 version and only if V_{CC} is between 4.75 V and 5.25 V
§ All typical values are at V_{CC} = 5 V, T_A = 25°C.
¶ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, I_{OS}.

switching characteristics (see Figure 1)

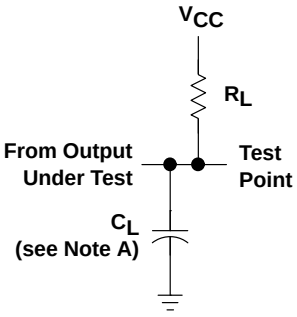
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC} = 4.5 V to 5.5 V, C_L = 50 pF, R1 = 500 Ω, R2 = 500 Ω, T_A = MIN to MAX†		UNIT
			MIN	MAX	
t_{PLH}	D	Q	2	13	ns
t_{PHL}			4	18	
t_{PLH}	LE	Q	5	21	ns
t_{PHL}			8	26	
t_{PLH}	$\overline{PRE}$	Q	6	22	ns
t_{PHL}	$\overline{CLR}$		6	24	
t_{PZH}	$\overline{OE}$	Q	3	16	ns
t_{PZL}			5	18	
t_{PHZ}	$\overline{OE}$	Q	1	11	ns
t_{PLZ}			2	12	

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

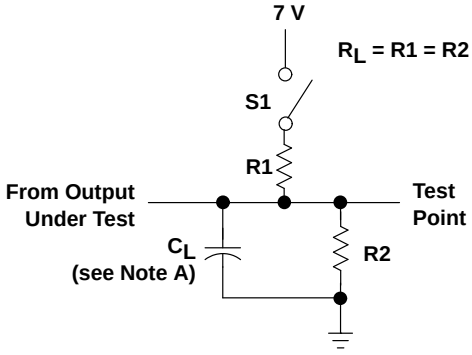
PARAMETER MEASUREMENT INFORMATION
SERIES 54ALS/74ALS AND 54AS/74AS DEVICES



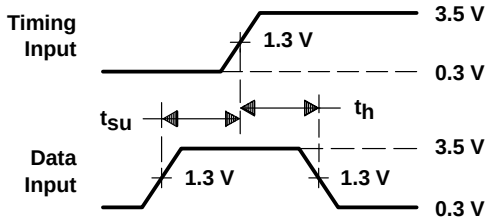
LOAD CIRCUIT FOR
BI-STATE
TOTEM-POLE OUTPUTS



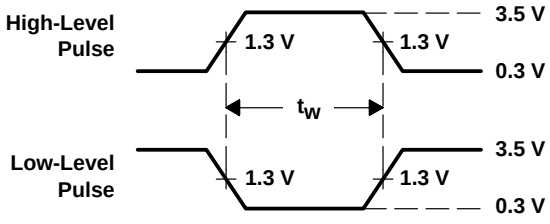
LOAD CIRCUIT
FOR OPEN-COLLECTOR OUTPUTS



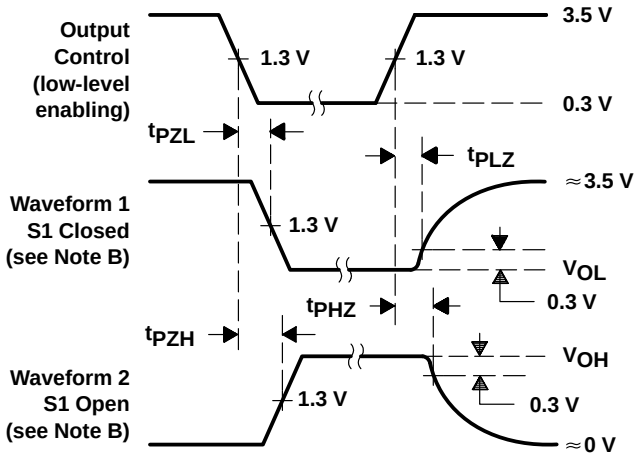
LOAD CIRCUIT
FOR 3-STATE OUTPUTS



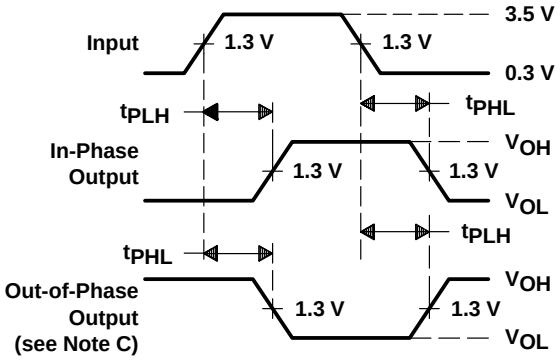
VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS
PULSE DURATIONS



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES, 3-STATE OUTPUTS



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES

NOTES: A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. When measuring propagation delay items of 3-state outputs, switch S1 is open.
D. All input pulses have the following characteristics: PRR ≤ 1 MHz, $t_r = t_f$ = 2 ns, duty cycle = 50%.
E. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuits and Voltage Waveforms

IMPORTANT NOTICE

Texas Instruments (TI) reserves the right to make changes to its products or to discontinue any semiconductor product or service without notice, and advises its customers to obtain the latest version of relevant information to verify, before placing orders, that the information being relied on is current.

TI warrants performance of its semiconductor products and related software to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

Certain applications using semiconductor products may involve potential risks of death, personal injury, or severe property or environmental damage ("Critical Applications").

TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, INTENDED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT APPLICATIONS, DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS.

Inclusion of TI products in such applications is understood to be fully at the risk of the customer. Use of TI products in such applications requires the written approval of an appropriate TI officer. Questions concerning potential risk applications should be directed to TI through a local SC sales office.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards should be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance, customer product design, software performance, or infringement of patents or services described herein. Nor does TI warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used.